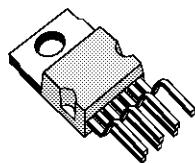

VERTICAL DEFLECTION BOOSTER

ADVANCE DATA

- POWER AMPLIFIER
- THERMAL PROTECTION
- OUTPUT CURRENT UP TO 2.0A_{PP}
- FLYBACK VOLTAGE UP TO 90V (on Pin 5)
- INTERNAL REFERENCE VOLTAGE
- EXTERNAL FLYBACK SUPPLY



HEPTAWATT
(Plastic Package)

ORDER CODE : STV9378F

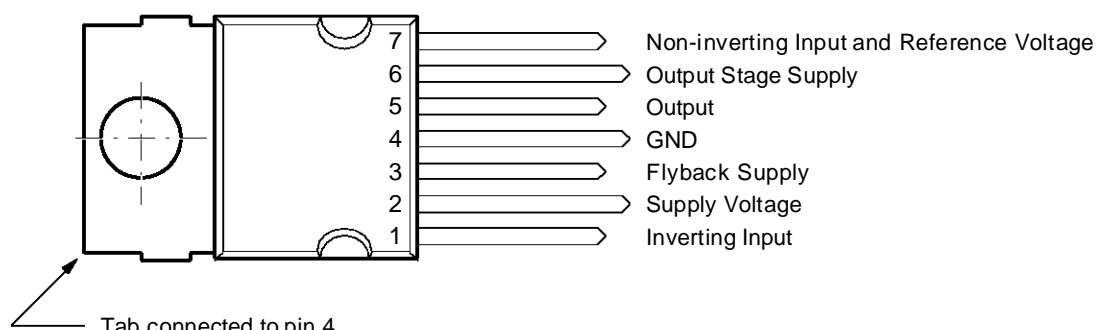
DESCRIPTION

Designed for monitors and high performance TVs, the STV9378F vertical deflection booster can handle flyback voltage up to 90V. More than this it is possible to have a flyback voltage which is more than the double of the supply (Pin 2). This allows to decrease the power consumption or to decrease the flyback time for a given supply voltage.

The STV9378F operates with supplies up to 42V and provides up to 2App output current to drive the yoke.

The STV9378F is offered in HEPTAWATT package.

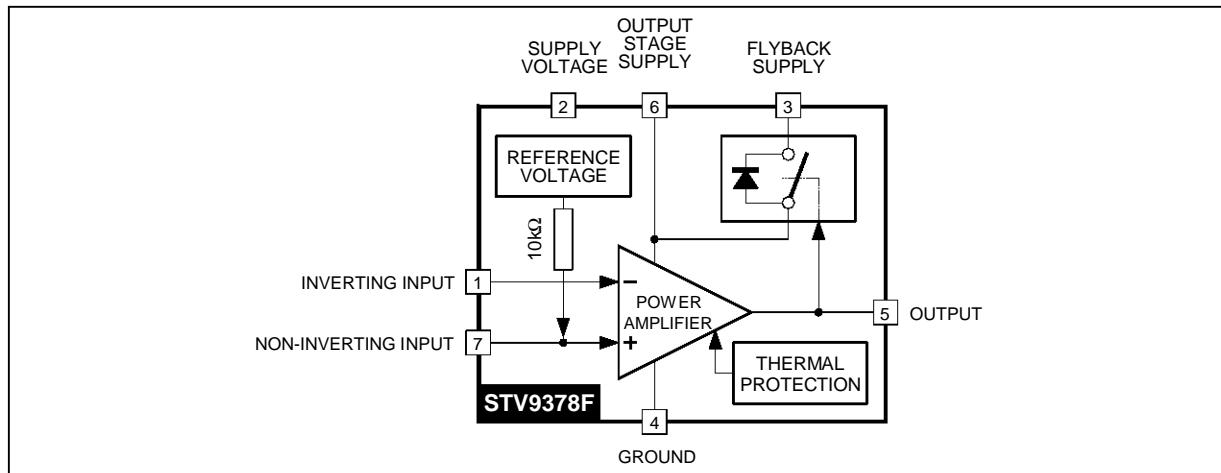
PIN CONNECTIONS



9378F-01.EPS

STV9378F

BLOCK DIAGRAM



9378F-02.EPS

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_S	Supply Voltage (Pin 2) (see note 1)	50	V
V_6	Flyback Peak Voltage (Pin 6) (see note 1)	100	V
V_1, V_7	Amplifier Input Voltage (Pins 1-7) (see note 1)	- 0.3, + V_S	V
I_O	Maximum Output Peak Current (see notes 2 and 3)	1.5	A
I_3	Maximum Sink Current ($t < 1\text{ms}$)	1.5	A
I_3	Maximum Source Current ($t < 1\text{ms}$) (in the diode, see Block Diagram)	1.5	A
$V_3 - V_2$	Voltage Difference between Flyback Supply and Supply Voltage	70	V
T_{oper}	Operating Ambient Temperature	- 20, + 75	$^{\circ}\text{C}$
T_{stg}	Storage Temperature	- 40, + 150	$^{\circ}\text{C}$
T_j	Junction Temperature	+150	$^{\circ}\text{C}$

9378F-01.TBL

- Notes :**
1. Versus GND.
 2. The output current can reach 4A peak for $t \leq 10\mu\text{s}$ (up to 120Hz).
 3. Provided SOAR is respected (see Figures 1 and 2).

THERMAL DATA

Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	Junction-case Thermal Resistance Max.	3	$^{\circ}\text{C/W}$
T_t	Temperature for Thermal Shutdown	150	$^{\circ}\text{C}$
ΔT_t	Hysteresis on T_t	10	$^{\circ}\text{C}$
T_{jr}	Recommended Max. Junction Temperature	120	$^{\circ}\text{C}$

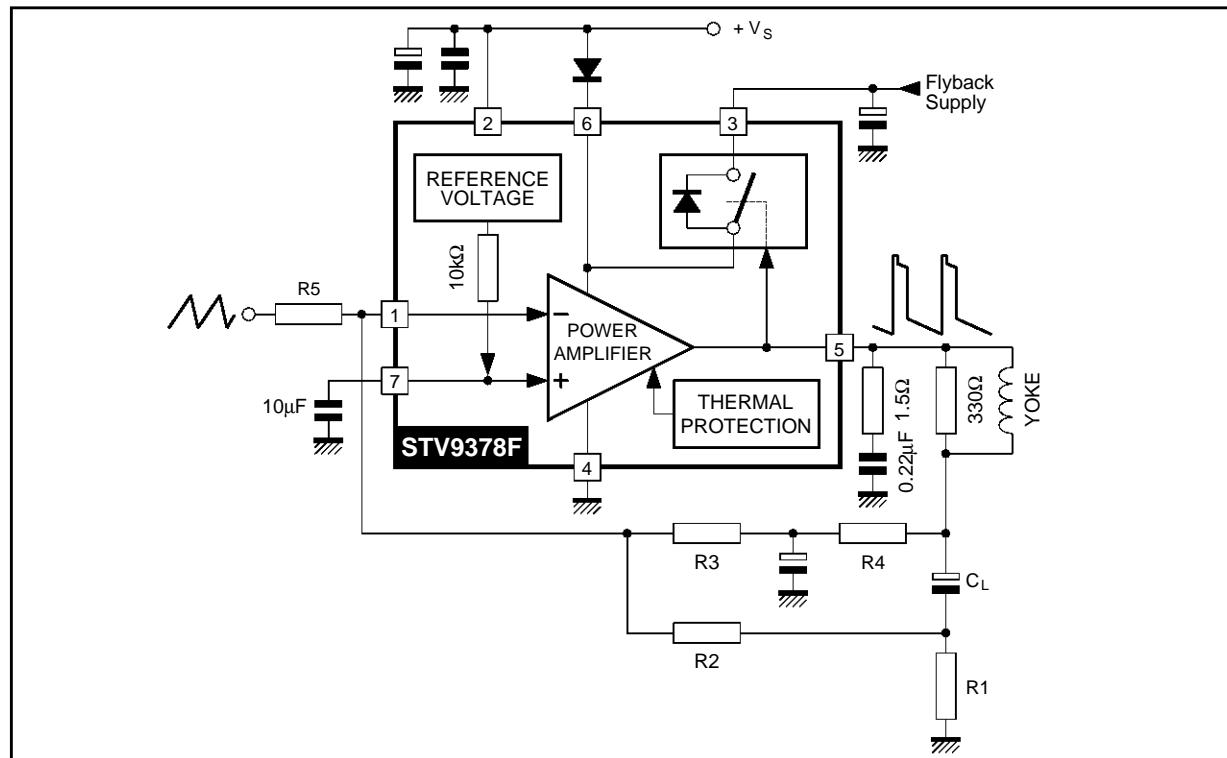
9378F-02.TBL

ELECTRICAL CHARACTERISTICS

(Vs = 42V, TA = 25°C, unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
Vs	Operating Supply Voltage Range		10		42	V
V3M	Operating Flyback Supply Voltage		Vs		90	V
I2	Pin 2 Quiescent Current	I3 = 0, I5 = 0		10	20	mA
I6	Pin 6 Quiescent Current	I3 = 0, I5 = 0	5	10	30	mA
Io	Max. Peak Output Current				1	A
I1	Amplifier Bias Current	V1 = 1V		- 0.15	- 1	µA
V7	Internal Reference Voltage		2.2	2.3	2.4	V
$\frac{\Delta V_7}{\Delta V_S}$	Reference Voltage Drift versus Vs	Vs = 24 to 42V		2	4	mV/V
Kt	Reference Voltage Drift versus Tj			100	150	ppm/°C
GV	Voltage Gain		80			dB
V5L	Output Saturation Voltage to GND (Pin 4)	I5 = 1A		1	1.5	V
V5H	Output Saturation Voltage to Supply (Pin 6)	I5 = - 1A		1.6	2.1	V
Vd5-6	Diode Forward Voltage between Pins 5-6	I5 = 1A		1.5	2	V
Vd3-6	Diode Forward Voltage between Pins 3-6	I3 = 1A		1.5	2	V
V3-6	Voltage Drop between Pins 3-6 (2nd part of flyback)	I3 = - 1A		2.1	2.9	V

9378F-03.TBL

APPLICATION CIRCUIT

9378F-03.EPS

STV9378F

Figure 1 : Output Transistors SOA
(for secondary breakdown)

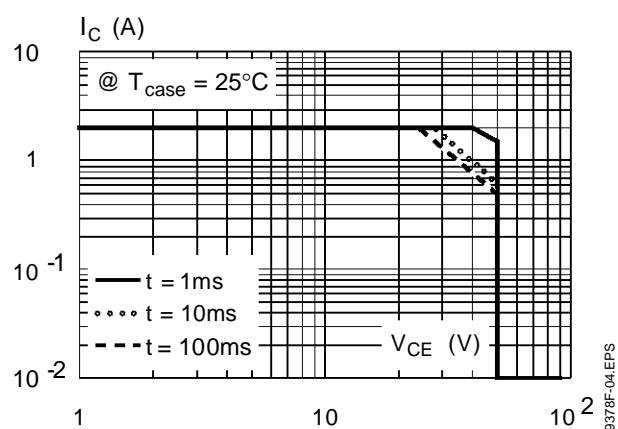
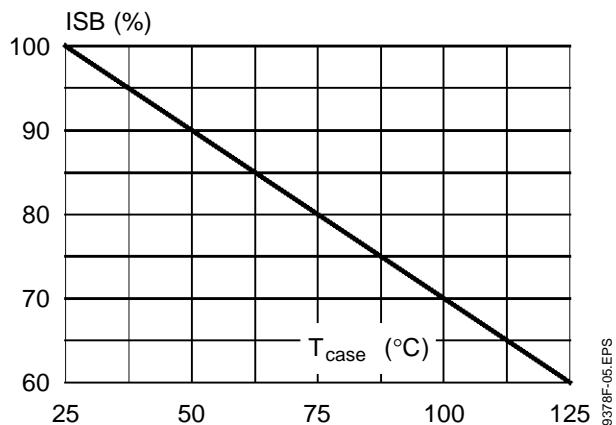
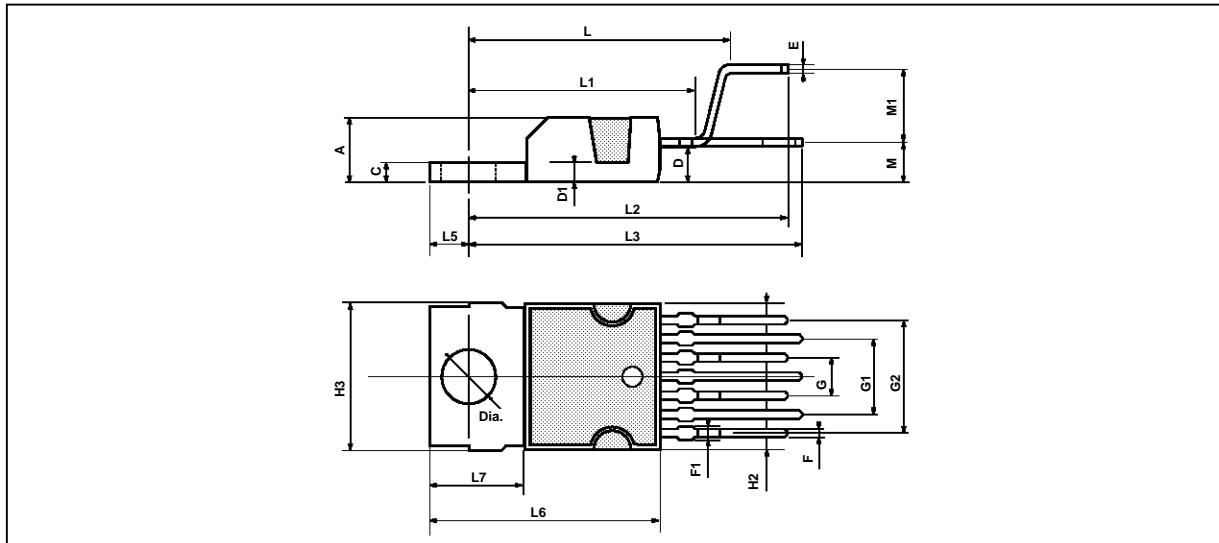


Figure 2 : Secondary Breakdown Temperature Derating Curve
(ISB = secondary breakdown current)



PACKAGE MECHANICAL DATA : 7 PINS - PLASTIC HEPTAWAT



PM-HEPTV.EPS

HEPTV.TBL

Dimensions	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			4.8			0.189
C			1.37			0.054
D	2.4		2.8	0.094		0.110
D1	1.2		1.35	0.047		0.053
E	0.35		0.55	0.014		0.022
F	0.6		0.8	0.024		0.031
F1			0.9			0.035
G	2.41	2.54	2.67	0.095	0.100	0.105
G1	4.91	5.08	5.21	0.193	0.200	0.205
G2	7.49	7.62	7.8	0.295	0.300	0.307
H2			10.4			0.409
H3	10.05		10.4	0.396		0.409
L		16.97			0.668	
L1		14.92			0.587	
L2		21.54			0.848	
L3		22.62			0.891	
L5	2.6		3	0.102		0.118
L6	15.1		15.8	0.594		0.622
L7	6		6.6	0.236		0.260
M		2.8			0.110	
M1		5.08			0.200	
Dia.	3.65		3.85	0.144		0.152

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